

Case Docket No. CTJPL.008A Date: December 10, 2003

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants

Graetz, et al.

Appl. No.

10/660,382

Filed

September 10, 2003

For

HIGH-CAPACITY

NANOSTRUCTURED SILICON AND LITHIUM

ALLOYS THEREOF

Examiner

Unknown

Group Art Unit:

Unknown

I hereby certify that this correspondence and all marked attachments are being deposited with the United States Postal Service as first class mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on

December 10, 2003

Pui Tong Ho, Reg. No. 44,155

TRANSMITTAL LETTER

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Dear Sir:

Enclosed for filing in the above-identified application are:

- -(X) An Information Disclosure Statement.
- (X) A PTO Form 1449 with 6 references.
- (X) The Commissioner is hereby authorized to charge any additional fees which may be required, or credit any overpayment, to Account No. 11-1410.
- (X) Return prepaid postcard.

Pui Tong Ho

Registration No. 44,155

Attorney of Record

Customer No. 20,995

(949) 760-0404

Docket No.: CTJPL.008A Customer No. 20,995

INFORMATION DISCLOSURE STATEMENT

: Graetz, et al.

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Unknown

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Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Dear Sir:

Enclosed is form PTO-1449 listing 6 references. Copies of disclosed U.S. patents and/or publications are not included pursuant to PTO waiver of the requirement under 37 C.F.R. § 1.98(a)(2)(i) for applications filed after June 30, 2003. Copies of other references, if listed, are enclosed.

This Information Disclosure Statement is being filed before the receipt of a first Office Action on the merits, and presumably no fee is required in accordance with 37 C.F.R. § 1.97(b)(3). If a first Office Action on the merits was mailed before the mailing date of this Statement, the Commissioner is authorized to charge the fee set forth in 37 C.F.R. § 1.17(p) to Deposit Account No. 11-1410.

Respectfully submitted,

KNOBBE, MARTENS, OLSON & BEAR, LLP

Pui Tong Ho

Registration No. 44,155

Attorney of Record

Customer No. 20,995

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· V	ROEMARK	OFC			U.S.	PATENT DOCUMENTS			
٠	EXAMINER INITIAL		OCUMENT NUMBER	DATE		NAME	CLASS	SUBCLASS	FILING DATE (IF APPROPRIATE)
		1	US 6,334,939 B1	1/1/02	Zhou, e	et al.	204	409	6/15/00

EXAMINER INITIAL	OTHER DOCUMENTS (INCLUDING AUTHOR, TITLE, DATE, PERTINENT PAGES, ETC.)				
	2	K. Sayama, H. Yagi, Y. Kato, S. Matsuta, H. Tarui, and S. Fujitani, Abstract 52, The 11th International Meeting on Lithium Batteries, Monterey, CA, June 23-28, 2002			
	3	T. Takamura, S. Ohara, J. Suzuki, and K. Sekine, Abstract 257, The 11th International Meeting on Lithium Batteries, Monterey, CA, June 23-28, 2002			
	4	A High Capacity Nano-Si Composite Anode Material for Lithium Rechargeable Batteries, Li, et al., Electrochemical and Solid-State Letters, 2 (11) 547-549 (1999)			
	5	Li Insertion/Extraction Reaction at a Si Film Evaporated on a Ni Foil, Ohara, et al., Journal of Power Sources 119-121 (2003) 591-596			
	6	Highly Reversible Lithium Storage in Nanostructured Silicon, Graetz, et al., Electrochemical and Solid-State Letters, 6 (9) A194-A197 (2003)			

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EXAMINER

DATE CONSIDERED